MC10EPT20

LVTTL/LVCMOS to **Differential LVPECL Translator**

The MC10EPT20 is a LVTTL/LVCMOS to differential LVPECL translator. Because LVPECL (Positive ECL) levels are used only +3.3V and ground are required. The small outline 8-lead SOIC package and the single gate of the EPT20 makes it ideal for those applications where space, performance, and low power are at a premium.

- 390ps Typical Propagation Delay
- High Bandwidth to 1.0 GHz Typical
- Differential LVPECL Outputs
- Small Outline SOIC Package
- PNP LVTTL Inputs for Minimal Loading
- VCC Range of 3.0V to 3.6V
- ESD Protection: >1.5KV HBM, >200V MM
- Q Output will default HIGH with inputs open
- Moisture Sensitivity Level 1, Indefinite Time Out of Drypack. For Additional Information, See Application Note AND8003/D
- Flammability Rating: UL-94 code V-0 @ 1/8", Oxygen Index 28 to 34
- Transistor Count = 150 devices

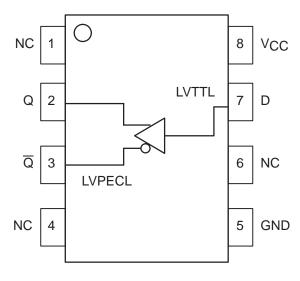


Figure 1. 8-Lead Pinout (Top View) and Logic Diagram

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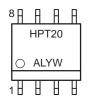
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MARKING DIAGRAM

CASE 751



A = Assembly Location

L = Wafer Lot

Y = Year

W = Work Week

*For additional information, see Application Note AND8002/D

PIN DESCRIPTION						
FUNCTION						
Differential LVPECL Outputs						
LVTTL Input						
Positive Supply						
Ground						

ORDERING INFORMATION

Device	Package	Shipping
MC10EPT20D	SOIC	98 Units/Rail
MC10EPT20DR2	SOIC	2500 Tape & Reel

MC10EPT20

MAXIMUM RATINGS*

Symbol	Parameter	Value	Unit	
Vcc	Power Supply		6.0 to 0	VDC
VI	Input Voltage (V _I not more positive than V _{CC})	6.0 to 0	VDC	
lout	Output Current	50 100	mA	
TA	Operating Temperature Range	-40 to +85	°C	
T _{stg}	Storage Temperature	-65 to +150	°C	
θЈΑ	Thermal Resistance (Junction–to–Ambient)	190 130	°C/W	
θЈС	Thermal Resistance (Junction-to-Case)	41 to 44 ± 5%	°C/W	
T _{sol}	Solder Temperature (<2 to 3 Seconds: 245°C des	265	°C	

^{*} Maximum Ratings are those values beyond which damage to the device may occur.

LVTTL INPUT DC CHARACTERISTICS ($V_{CC} = 3.3V \pm 0.3V$; GND = 0V; $T_A = -40^{\circ}C$ to +85°C)

Symbol	Characteristic	Min	Тур	Max	Unit
lН	Input HIGH Current (V _{in} = 2.7V)			20	μΑ
Iнн	Input HIGH Current MAX (Vin = 6.0V)			100	μΑ
IIL	Input LOW Current (V _{in} = 0.5V)			-0.6	mA
VIK	Input Clamp Voltage (I _{in} = -18mA)			-1.2	V
VIH	Input HIGH Voltage	2.0			V
V _{IL}	Input LOW Voltage			0.8	V

LVPECL OUTPUT DC CHARACTERISTICS ($V_{CC} = 3.3V \pm 0.3V$; GND = 0V) (Note 3.)

		–40°C			25°C			85°C			
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
ICC	Power Supply Current HIGH (Note 1.)	15	23	31	15	23	31	15	23	31	mA
VOH	Output HIGH Voltage (Note 3.)	2165	2310	2415	2230	2355	2480	2290	2375	2540	mV
VOL	Output LOW Voltage (Note 3.)	1365	1550	1615	1430	1570	1680	1490	1580	1740	mV

NOTE: 10EP circuits are designed to meet the DC specifications shown in the above table after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse airflow greater than 500lfpm is maintained.

- 1. $V_{CC} = 3.3V$, GND = 0V, all other pins floating.
- All loading with 50 ohms to V_{CC}-2.0 volts.
 Output parameters vary 1:1 with V_{CC}.

AC CHARACTERISTICS ($V_{CC} = 3.3V \pm 0.3V$; GND = 0V)

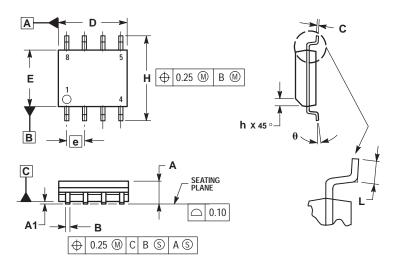
		–40°C		25°C			85°C				
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
f _{max}	Maximum Toggle Frequency (Note 4.)		1000			1000			1000		MHz
tPLH, tPHL	Propagation Delay to Output Differential	150	350	600	150	370	600	150	380	600	ps
^t JITTER	Cycle-to-Cycle Jitter		TBD			TBD			TBD		ps
t _r t _f	Output Rise/Fall Times (20% – 80%) Q, $\overline{\mathbb{Q}}$	50	100	180	60	120	200	70	140	220	ps

^{4.} F_{max} guaranteed for functionality only. V_{OL} and V_{OH} levels are guaranteed at DC only.

MC10EPT20

PACKAGE DIMENSIONS

SO-8 **D SUFFIX** PLASTIC SOIC PACKAGE CASE 751-06 ISSUE T



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 2. DIMENSIONS ARE IN MILLIMETER.
 3. DIMENSION D AND E DO NOT INCLUDE MOLD PROTRUSION.
 4. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
 5. DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 TOTAL IN EXCESS OF THE B DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIMETERS							
DIM	MIN MAX							
Α	1.35	1.75						
A1	0.10	0.25						
В	0.35	0.49						
С	0.19	0.25						
D	4.80	5.00						
Ε	3.80	4.00						
е	1.27	BSC						
Н	5.80	6.20						
h	0.25	0.50						
L	0.40	1.25						
θ	0° 7°							

MC10FPT20

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